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1,4-Bis(thiophen-2-vl)butane-1,4-dione

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Key indicators: single-crystal X-ray study; T = 296 K; mean $\sigma(C-C) = 0.005$ Å; R factor = 0.062; wR factor = 0.200; data-to-parameter ratio = 14.0.

In the centrosymmetric title compound, $C_{12}H_{10}O_2S_2$, the alkyl chains adopt a fully extended all-trans conformation with respect to the C(thiophene)—C bond. The non-H atoms of the molecule are nearly planar, with a maximum deviation of 0.063 (2) Å from the mean plane of the constituent atoms. In the crystal, symmetry-related molecules are linked via pairs of C—H··· π contacts [H–centroid distances of the thiophene units = 2.79 (9) and 2.82 (4) Å], in turn interdigitating with each other along the bc plane, thus leading to an interwoven two-dimensional network.

Related literature

For related structures, see: Becerra *et al.* (2010); Liu *et al.* (2008); Nair, Devipriya & Eringathodi (2007); Nair, Vellalath *et al.* (2007); Bushueva *et al.* (2010). For background information on applications, see: Atalar *et al.* (2009); Chen *et al.* (2009); Charati *et al.* (2008); Cao *et al.* (2008); Wu *et al.* (2008). For the synthetic procedure, see: Schweiger *et al.* (2000). For bond lengths, see: Allen *et al.* (1987). For related $C-H\cdots\pi$ hydrogen bonds, see: Hu *et al.* (2008); Ishihara *et al.* (2007); Jennings *et al.* (2001).

Experimental

Crystal data

 $C_{12}H_{10}O_2S_2$ $M_r = 250.34$ Monoclinic, $P2_1/n$ a = 5.6345 (3) Å b = 6.2244 (3) Å c = 16.3779 (9) Å $\beta = 92.902$ (4)° V = 573.66 (5) Å³ Z = 2Mo $K\alpha$ radiation $\mu = 0.44 \text{ mm}^{-1}$ T = 296 K $0.20 \times 0.15 \times 0.10 \text{ mm}$ Data collection

Bruker SMART CCD area-detector diffractometer Absorption correction: multi-scan

Absorption correction: multi-sca (SADABS; Sheldrick, 1996) $T_{min} = 0.957, T_{max} = 0.978$ 2000 measured reflections 1023 independent reflections 838 reflections with $I > 2\sigma(I)$ $R_{\rm int} = 0.021$

Refinement

 $R[F^2 > 2\sigma(F^2)] = 0.062$ $wR(F^2) = 0.200$ S = 1.091023 reflections 73 parameters H-atom parameters constrained $\Delta \rho_{\rm max} = 0.58 \ {\rm e} \ {\rm \AA}^{-3}$ $\Delta \rho_{\rm min} = -0.35 \ {\rm e} \ {\rm Å}^{-3}$

Table 1Hydrogen-bond geometry (Å, °).

Cg1 is the centroid of the C1-C4/S1 ring.

$D-\mathrm{H}\cdots A$	D-H	$H \cdot \cdot \cdot A$	$D \cdot \cdot \cdot A$	$D-\mathrm{H}\cdots A$
$ \begin{array}{c} C1 - H1 \cdots Cg1^{i} \\ C6 - H6B \cdots Cg1^{ii} \end{array} $	0.93	2.79 (9)	3.610 (5)	146
	0.97	2.82 (4)	3.637 (4)	143

Symmetry codes: (i) $-x + \frac{3}{2}$, $y - \frac{1}{2}$, $-z + \frac{3}{2}$; (ii) -x + 2, -y, -z + 1.

Data collection: *SMART* (Bruker, 2007); cell refinement: *SAINT* (Bruker, 2007); data reduction: *SAINT*; program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008); software used to prepare material for publication: *SHELXTL*.

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Supplementary data and figures for this paper are available from the IUCr electronic archives (Reference: ZJ2057).

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 $\textbf{0690} \quad \text{Guo et al.} \quad \textbf{C}_{12} \textbf{H}_{10} \textbf{O}_2 \textbf{S}_2 \\ \quad \textbf{Acta Cryst. (2012)}. \quad \textbf{E68, 0689-0690}$

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1,4-Bis(thiophen-2-yl)butane-1,4-dione

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Comment

Electroactive and photoactive thiophene-based molecules, oligomers, and polymers (Atalar et al., 2009; Chen et al., 2009; Charati et al., 2008; Becerra et al., 2010; Liu et al., 2008; Nair, Devipriya & Eringathodi, 2007; Nair, Vellalath et al., 2007; Bushueva et al.; 2010) are important for advanced technological applications, including display technologies, field-effect transistors, solar cells, sensors, nonlinear optics, molecular wires, and diodes (Cao et al., 2008; Wu et al., 2008). Thiophenes and its derivatives are originally applied to synthesize thiophene-based compounds, such as, oligomers and polythiophenes due to easy electropolymerization of thiophenes to produce stable, electrically conductive polymeric films. Thiophenes and its derivatives can also be widely used as building blocks in many agrochemicals and pharmaceuticals. To investigate the relationship between structure and pharmacological activity, the title compound was synthesized and its structure was determined by X-ray diffraction. As shown in figure 1, the centrosymmetric title compound lies across a crystallographic inversion centre which is situated at the midpoint of the C6–C6A (1.512 (8) Å, symmetry code: (A) 2-x, 1-y, 1-z) bond. The alkyl chains attached thiophenes adopt a fully extended all-trans conformation with respect to the Cthiophene-C bond. The non-H atoms of the molecule is nearly planar with O1 and O1A maximum deviation of 0.063 (2) Å from the mean plane of its constituting atoms. The C1-S1 and C4-S1 bond length of 1.678 (5) and 1.697 (4) Å, respectively, correspond to typical single C-S bonds. Whereas the C1-O1 (1.215 (5) Å) bond length indicate the presence of a typical double C=O bond (Allen et al., 1987). It is well-established that weak bonding interactions between entities, such as hydrogen-bonding and π -stacking, are important supramolecular forces, which can be used to govern the process of molecular recognition and selfassembly (Hu et al., 2008; Ishihara et al., 2007; Jennings et al., 2001). In the crystal structure, it is noteworthy that symmetry-related molecules, in turn, are linked via pairs of intermolecular C—H··· π constacts [H–centroid distance of the thiophene units = 2.79 (9) - 2.82 (4) Å], and interdigitated with each other along bc plane, thus leading to an interwoven two dimensional network.

Experimental

Reagents and solvents were of commercially available quality. The title compound was synthesized according to the method of Schweiger *et al.* 2000. To a suspension of AlCl₃ (16 g, 0.12 mol) in CH₂Cl₂ (15 ml) a solution of thiophene (10 ml, 0.12 mol) and succinyl chloride (6 ml, 0.05 mol) in CH₂Cl₂ was added dropwise. The red mixture was stirred at r.t. for 18 h. This was then quenched with ice and conc. HCl (5 ml). After intensive stirring for 2 h the dark green organic phase was separated, washed with 2 M HCl, H₂O NaHCO₃ solution and dried over MgSO₄. After evaporation of the solvent a blue-green solid remained, which was suspended in ethanol. Filtration and washing with ethanol and diethyl ether provided a green solid. Column chromatography (SiO₂, CH₂Cl₂-hexane (1 : 1)) obtains (I) as a white solid 6.74 g (26.87 mmol; 54%). Single crystals suitable for X-ray diffraction were prepared by slow evaporation of a solution of the crude (5 g) in a mixture of water/ethanol (20 ml, 1:1, ν/ν) at room temperature.

Refinement

All H atoms were placed in idealized positions (C—H = 0.93–0.97 Å) and refined as riding atoms with $U_{iso}(H) = 1.2U_{eq}(C)$.

Computing details

Data collection: *SMART* (Bruker, 2007); cell refinement: *SAINT* (Bruker, 2007); data reduction: *SAINT* (Bruker, 2007); program(s) used to solve structure: *SHELXS97* (Sheldrick, 2008); program(s) used to refine structure: *SHELXL97* (Sheldrick, 2008); molecular graphics: *SHELXTL* (Sheldrick, 2008); software used to prepare material for publication: *SHELXTL* (Sheldrick, 2008).

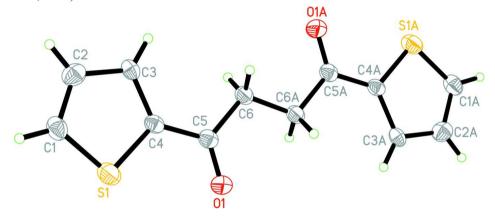


Figure 1

The molecular structure of the title compound, with displacement ellipsoids at the 30% probability level (Symmetry code: (A) 2-x, 1-y, 1-z).

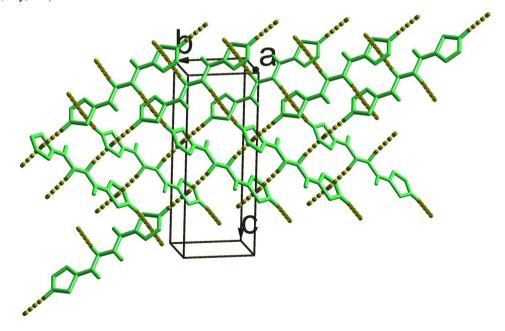


Figure 2

The C-H··· π stacking interactions (dashed lines) in the structure of the title compound viewing along bc plane, H atoms have been omitted for clarity, except for those involved in C-H··· π stacking interactions.

1,4-Bis(thiophen-2-yl)butane-1,4-dione

Crystal data

F(000) = 260 $C_{12}H_{10}O_2S_2$ $M_r = 250.34$ $D_{\rm x} = 1.449 \; {\rm Mg \; m^{-3}}$ Monoclinic, $P2_1/n$ Mo $K\alpha$ radiation, $\lambda = 0.71073 \text{ Å}$ Hall symbol: -P 2yn Cell parameters from 1252 reflections a = 5.6345 (3) Å $\theta = 2.6-22.6^{\circ}$ b = 6.2244 (3) Å $\mu = 0.44 \text{ mm}^{-1}$ c = 16.3779 (9) ÅT = 296 K $\beta = 92.902 (4)^{\circ}$ Bolck, vellow $V = 573.66 (5) \text{ Å}^3$ $0.20 \times 0.15 \times 0.10 \text{ mm}$ Z = 2

Data collection

Bruker SMART CCD area-detector 2000 measured reflections diffractometer 1023 independent reflections Radiation source: fine-focus sealed tube 838 reflections with $I > 2\sigma(I)$ $R_{\rm int} = 0.021$ Graphite monochromator φ and ω scans $\theta_{\text{max}} = 25.1^{\circ}, \ \theta_{\text{min}} = 3.5^{\circ}$ $h = -5 \rightarrow 6$ Absorption correction: multi-scan $k = -7 \rightarrow 6$ (SADABS; Sheldrick, 1996) $T_{\text{min}} = 0.957$, $T_{\text{max}} = 0.978$ $l = -19 \rightarrow 19$

Refinement

Refinement on F^2 Secondary atom site location: difference Fourier Least-squares matrix: full map $R[F^2 > 2\sigma(F^2)] = 0.062$ Hydrogen site location: inferred from $wR(F^2) = 0.200$ neighbouring sites S = 1.09H-atom parameters constrained 1023 reflections $w = 1/[\sigma^2(F_0^2) + (0.105P)^2 + 0.7893P]$ 73 parameters where $P = (F_0^2 + 2F_c^2)/3$ 0 restraints $(\Delta/\sigma)_{\text{max}} < 0.001$ $\Delta \rho_{\rm max} = 0.58 \text{ e Å}^{-3}$ Primary atom site location: structure-invariant direct methods $\Delta \rho_{\min} = -0.35 \text{ e Å}^{-3}$

Special details

Geometry. All esds (except the esd in the dihedral angle between two l.s. planes) are estimated using the full covariance matrix. The cell esds are taken into account individually in the estimation of esds in distances, angles and torsion angles; correlations between esds in cell parameters are only used when they are defined by crystal symmetry. An approximate (isotropic) treatment of cell esds is used for estimating esds involving l.s. planes.

Refinement. Refinement of F^2 against ALL reflections. The weighted R-factor wR and goodness of fit S are based on F^2 , conventional R-factors R are based on F, with F set to zero for negative F^2 . The threshold expression of $F^2 > 2 \operatorname{sigma}(F^2)$ is used only for calculating R-factors(gt) etc. and is not relevant to the choice of reflections for refinement. R-factors based on F^2 are statistically about twice as large as those based on F, and R- factors based on ALL data will be even larger.

Fractional atomic coordinates and isotropic or equivalent isotropic displacement parameters (\hat{A}^2)

	x	у	Z	$U_{ m iso}$ */ $U_{ m eq}$	
S1	1.1013 (2)	-0.0356(2)	0.69663 (7)	0.0577 (5)	
C4	0.9593 (6)	0.0981 (6)	0.6181 (2)	0.0376 (9)	
C5	1.0715 (7)	0.2877 (6)	0.5837 (2)	0.0403 (9)	
C3	0.7295 (7)	0.0004 (6)	0.5931(2)	0.0368 (9)	
Н3	0.6239	0.0483	0.5516	0.044*	

supplementary materials

C2	0.6983 (7)	-0.1823 (8)	0.6446 (3)	0.0537 (12)	
H2	0.5649	-0.2702	0.6398	0.064*	
C1	0.8824 (8)	-0.2171 (8)	0.7017(3)	0.0515 (11)	
H1	0.8850	-0.3295	0.7392	0.062*	
O1	1.2671 (5)	0.3465 (5)	0.6091 (2)	0.0592 (9)	
C6	0.9351 (7)	0.4030(7)	0.5154(2)	0.0419 (10)	
H6A	0.7830	0.4485	0.5346	0.050*	
H6B	0.9043	0.3038	0.4705	0.050*	

Atomic displacement parameters (\mathring{A}^2)

	U^{11}	U^{22}	U^{33}	U^{12}	U^{13}	U^{23}
S1	0.0511 (8)	0.0646 (9)	0.0569 (8)	0.0067 (5)	-0.0020 (5)	0.0135 (6)
C4	0.0371 (19)	0.040(2)	0.0356 (19)	0.0092 (16)	0.0000 (15)	-0.0042 (17)
C5	0.041(2)	0.040(2)	0.040(2)	0.0079 (17)	0.0006 (16)	-0.0056 (17)
C3	0.039(2)	0.038(2)	0.0348 (19)	0.0114 (16)	0.0097 (15)	0.0031 (16)
C2	0.042(2)	0.058(3)	0.062(3)	-0.002(2)	0.012(2)	-0.005 (2)
C1	0.047(2)	0.054(3)	0.055(2)	0.008(2)	0.0129 (19)	0.016(2)
O1	0.0523 (18)	0.057(2)	0.067(2)	-0.0076 (15)	-0.0175 (15)	0.0107 (17)
<u>C6</u>	0.045 (2)	0.039 (2)	0.041 (2)	0.0047 (18)	-0.0052 (16)	-0.0003 (18)

Geometric parameters (Å, °)

Geometrie par ameters (11,	,		
S1—C1	1.678 (5)	С3—Н3	0.9300
S1—C4	1.697 (4)	C2—C1	1.379 (6)
C4—C5	1.466 (6)	C2—H2	0.9300
C4—C3	1.470 (6)	C1—H1	0.9300
C5—O1	1.215 (5)	C6—C6 ⁱ	1.512 (8)
C5—C6	1.506 (5)	C6—H6A	0.9700
C3—C2	1.431 (6)	C6—H6B	0.9700
C1—S1—C4	92.8 (2)	C1—C2—H2	122.8
C5—C4—C3	128.1 (3)	C3—C2—H2	122.8
C5—C4—S1	119.4 (3)	C2—C1—S1	112.9 (3)
C3—C4—S1	112.5 (3)	C2—C1—H1	123.5
O1—C5—C4	120.8 (4)	S1—C1—H1	123.5
O1—C5—C6	122.1 (4)	C5—C6—C6 ⁱ	113.0 (4)
C4—C5—C6	117.1 (3)	C5—C6—H6A	109.0
C2—C3—C4	107.3 (3)	C6 ⁱ —C6—H6A	109.0
C2—C3—H3	126.4	C5—C6—H6B	109.0
C4—C3—H3	126.4	C6 ⁱ —C6—H6B	109.0
C1—C2—C3	114.5 (4)	H6A—C6—H6B	107.8
C1—S1—C4—C5	-179.8 (3)	S1—C4—C3—C2	-0.1 (4)
C1—S1—C4—C3	-0.1(3)	C4—C3—C2—C1	0.3 (5)
C3—C4—C5—O1	-177.6 (4)	C3—C2—C1—S1	-0.3(5)
S1—C4—C5—O1	2.0 (5)	C4—S1—C1—C2	0.2 (4)
C3—C4—C5—C6	1.7 (6)	O1—C5—C6—C6 ⁱ	-1.1 (7)

Acta Cryst. (2012). E68, o689–o690 sup-4

supplementary materials

Symmetry code: (i) -x+2, -y+1, -z+1.

Hydrogen-bond geometry (Å, °)

Cg1 is the centroid of the C1–C4/S1 or C1A–C4A/S1A ring.

<i>D</i> —H··· <i>A</i>	<i>D</i> —H	$H\cdots A$	D··· A	<i>D</i> —H··· <i>A</i>
C1—H1··· <i>Cg</i> 1 ⁱⁱ	0.93	2.79 (9)	3.610 (5)	146
C6—H6 <i>B</i> ··· <i>Cg</i> 1 ⁱⁱⁱ	0.97	2.82 (4)	3.637 (4)	143

Symmetry codes: (ii) -x+3/2, y-1/2, -z+3/2; (iii) -x+2, -y, -z+1.